

5430/DM5430/DM7430 8-Input NAND Gate

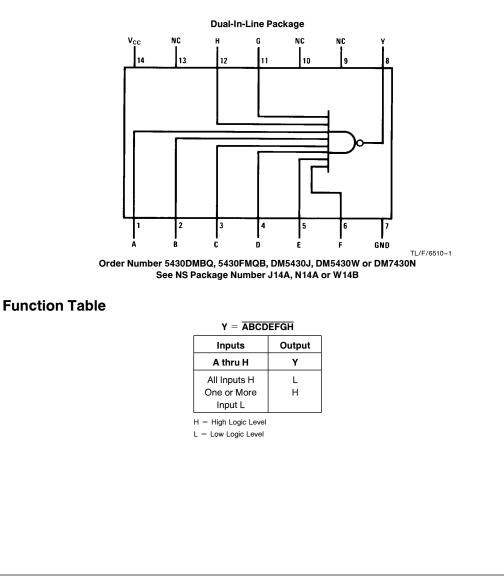
General Description

This device contains a single gate which performs the logic NAND function.

 Alternate Military/Aerospace device (5430) is available. Contact a National Semiconductor Sales Office/Distributor for specifications. 5430/DM5430/DM7430 8-Input NAND Gate

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Connection Diagram



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Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM54 and 54	-55°C to +125°C
DM74	$0^{\circ}C$ to $+70^{\circ}C$
Storage Temperature Range	-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	l Parameter	DM5430			DM7430			Units
Cymbol		Min	Nom	Max	Min	Nom	Max	onito
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High Level Input Voltage	2			2			V
VIL	Low Level Input Voltage			0.8			0.8	V
I _{OH}	High Level Output Current			-0.4			-0.4	mA
I _{OL}	Low Level Output Current			16			16	mA
Τ _Α	Free Air Operating Temperature	-55		125	0		70	°C

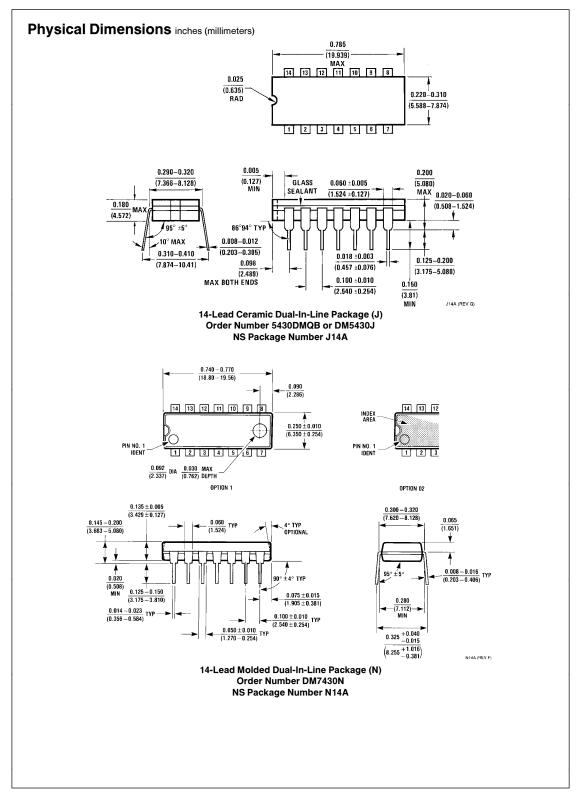
Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

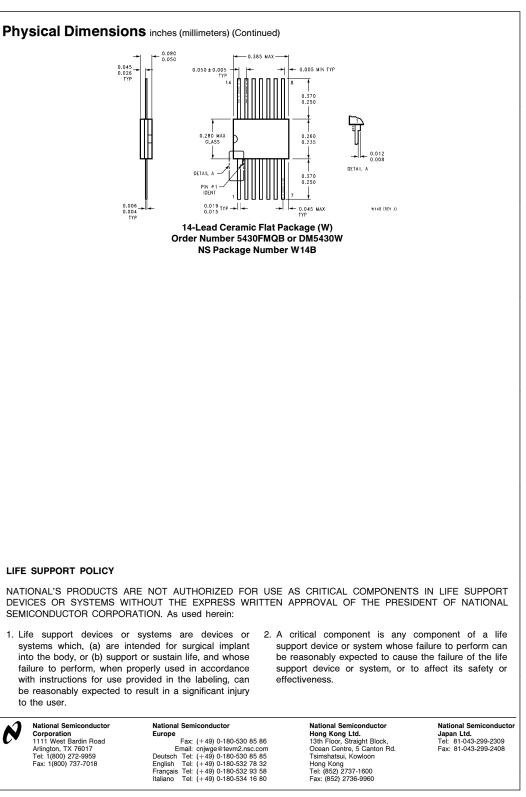
Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_1 =$	= -12 mA			-1.5	V
V _{OH}	High Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max$		2.4	3.4		v
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$			0.2	0.4	v
l _l	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$				1	mA
I _{IH}	High Level Input Current	$V_{CC} = Max, V_I = 2.4V$				40	μΑ
Ι _{ΙL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$				-1.6	mA
I _{OS}	Short Circuit	V _{CC} = Max	DM54	-20		-55	mA
	Output Current	(Note 2)	DM74	-18		-55	
ICCH	Supply Current with Outputs High	V _{CC} = Max			1	2	mA
I _{CCL}	Supply Current with Outputs Low	V _{CC} = Max			3	6	mA

Switching Characteristics at $V_{CC} = 5V$ and $T_A = 25^{\circ}C$ (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time Low to High Level Output	$C_{L} = 15 \text{ pF}$ $R_{L} = 400\Omega$		22	ns
t _{PHL}	Propagation Delay Time High to Low Level Output			15	ns

Note 2: Not more than one output should be shorted at a time.





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Datasheets for electronics components.

National Semiconductor was acquired by Texas Instruments.

http://www.ti.com/corp/docs/investor_relations/pr_09_23_2011_national_semiconductor.html

This file is the datasheet for the following electronic components:

DM7430 - http://www.ti.com/product/dm7430?HQS=TI-null-null-dscatalog-df-pf-null-wwe 5430 - http://www.ti.com/product/5430?HQS=TI-null-null-dscatalog-df-pf-null-wwe DM5430 - http://www.ti.com/product/dm5430?HQS=TI-null-null-dscatalog-df-pf-null-wwe